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Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China















SICR5650 / SICRB5650 / SICRD5650 / SICRF5650 650V SIC POWER SCHOTTKY RECTIFIER

Description

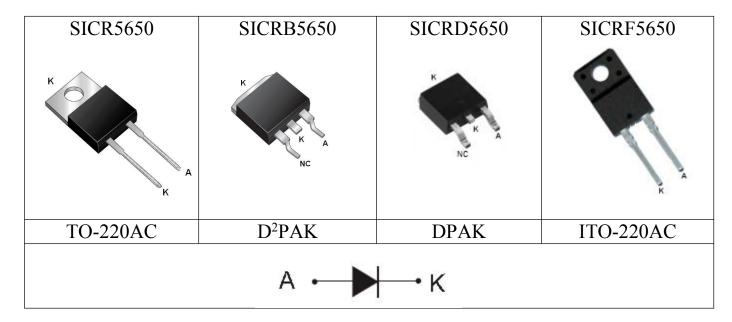
SICR5650/ SICRB5650/ SICRD5650/ SICRF5650 are all single SiC Schottky rectifiers packaged in TO-220AC, D2PAK, DPAK and ITO-220ACcase. The device is a high voltage Schottky rectifier that has very low total conduction losses and very stable switching characteristics over temperature extremes. The SICR5650/ SICRB5650/ SICRD5650/ SICRF5650 are ideal for energy sensitive, high frequency applications in challenging environments.

Applications

- Alternative energy inverters
- Power Factor Correction (PFC)
- Free-Wheeling diodes
- Switching supply output rectification
- Reverse polarity protection

Features

- 175°C T_J operation
- Ultra-low switching loss
- Switching speeds independent of operating temperature
- Low total conduction losses
- · High forward surge current capability
- High package isolation voltage
- Guard ring for enhanced ruggedness and long term reliability
- Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional electrical and life testing can be performed upon request



Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	650	٧
Average Rectified Forward Current	I _{F (AV)}	50% duty cycle @Tc=105°C, rectangular wave form	5	Α
Peak One Cycle Non-Repetitive Surge Current	I _{FSM}	8.3ms, Half Sine pulse	60	Α

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Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V _{F1} @ 5A, Pulse, T _J = 25 °C		1.5	1.7	V
	V _{F2}	@ 5A, Pulse, T _J = 150 °C	1.98	2.5	V
Reverse Current at DC condition*	I _{R1}	$@V_R = \text{rated } V_R$ $T_J = 25 ^{\circ}\text{C}$	5	60	μА
Reverse Current *	I _{R2}	$@V_R = \text{rated } V_R$ $T_J = 125 ^{\circ}\text{C}$	70	250	μА
Junction Capacitance	Ст	$@V_R = 5V, T_C = 25 °C$ $f_{SIG} = 1MHz$	-	TBD	pF
Series Inductance	Ls	Measured lead to lead 5 mm from package body	-	TBD	nH
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs
RSM Isolation Voltage (t = 1.0 second, R. H. < =30%, T _A = 25 °C)		Clip mounting, the epoxy body away from the heatsink edge by more than 0.110" along the lead direction.	-	4500	
	V _{ISO}	Clip mounting, the epoxy body is inside the heatsink.	-	3500	V
		Screw mounting, the epoxy body is inside the heatsink.	-	1500	

^{*} Pulse width < 300 µs, duty cycle < 2%

Thermal-Mechanical Specifications:

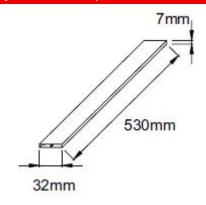
Characteristics	Symbol	SICR5650	SICRB5650	SICRD5650	SICRF5650	Units
Junction Temperature	TJ	-55 to +175			°C	
Storage Temperature	T _{stg}	-55 to +175			°C	
Maximum Thermal Resistance Junction to Case	$R_{ heta JC}$	2.4	2.4	2.4	4.2	°C/W

Ordering Information

Device	Package	Weight	Shipping
SICR5650	TO-220AC	1.8g	50pcs / tube
SICRB5650	D ² PAK	1.85g	800pcs / reel
SICRD5650	DPAK	0.39g	2500pcs / reel
SICRF5650	ITO-220AC	1.8g	50pcs / tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Tube Specification(TO-220AC/ITO-220AC)



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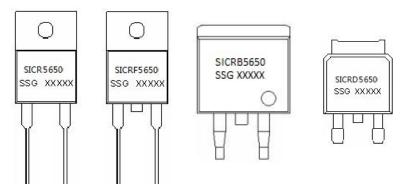
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Marking Diagram



Where XXXXX is YYWWL

SICR = Device Type B/D/F = Package type 5 = Forward Current (5A) 650 = Reverse Voltage (650V)

 SSG
 = SSG

 YY
 = Year

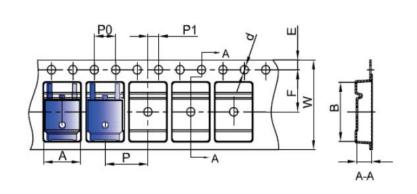
 WW
 = Week

 L
 = Lot Number

Cautions: Molding resin

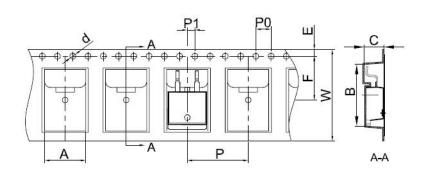
Epoxy resin UL:94V-0

Carrier Tape & Reel Specification DPAK



SYMBOL	Millimet	Millimeters			
STWBOL	Min.	Max.			
Α	6.80	7.00			
В	10.40	10.60			
С	2.60	2.80			
d	Ф1.45	Ф1.65			
E	1.65	1.85			
F	7.40	7.60			
P0	3.90	4.10			
Р	7.90	8.10			
P1	1.90	2.10			
W	15.90	16.30			

Carrier Tape & Reel Specification D2PAK



Millimeters		
Min.	Max.	
10.70	10.90	
16.03	16.23	
5.11	5.31	
1.45	1.65	
1.65	1.85	
11.40	11.60	
3.90	4.10	
15.90	16.10	
1.90	2.10	
23.90	24.30	
	Min. 10.70 16.03 5.11 1.45 1.65 11.40 3.90 15.90 1.90	

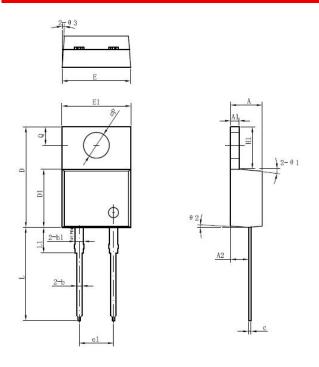
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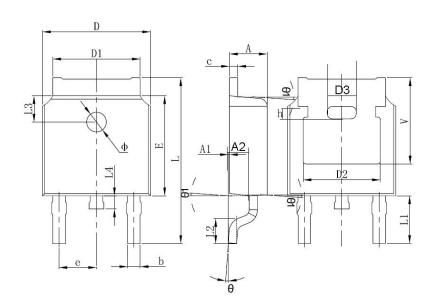


Mechanical Dimensions TO-220AC



Symbol	Dimensions in millimeters				
0,	Min.	Typical	Max.		
Α	4.47	4.70	4.85		
A1	1.17	1.27	1.37		
A2	2.52	2.69	2.89		
b	0.71	0.81	0.96		
b1	1.17	1.27	1.37		
С	0.31	0.38	0.61		
D	14.64	14.94	15.24		
D1	8.50	8.07	8.90		
E	10.01	10.16	10.31		
E1	9.98	10.18	10.38		
e1	4.98	5.08	5.18		
H1	6.04	6.24	6.44		
L	13.00	13.86	14.08		
L1	3.56	3.80	3.96		
ФР	3.74	3.84	4.04		
Q	2.54	2.74	2.94		
Θ1		5°			
Θ2		4°			
Θ3		4°			

Mechanical Dimensions DPAK



OVMDOL	Millimeters		Inc	hes
SYMBOL	Min.	Max.	Min.	Max.
Α	2.20	2.40	0.087	0.094
A1	0.00	0.127	0.000	0.005
b	0.66	0.86	0.026	0.034
С	0.46	0.60	0.018	0.024
D	6.50	6.70	0.256	0.264
D1	5.13	5.46	0.202	0.215
D2	4.83	REF.	0.190 REF.	
E	6.00	6.20	0.236	0.244
е	2.186	2.386	0.086	0.094
L	9.70	10.40	0.381	0.409
L1	2.90	REF.	0.144	REF.
L2	1.40	1.70	0.055	0.067
L3	1.60	REF.	0.063	REF.
L4	0.60	1.00	0.024	0.039
Ф	1.10	1.30	0.043	0.051
Θ	0°	8°	0°	8°
h	0.00	0.30	0.000	0.012
V	5.35 REF.		0.211	REF.

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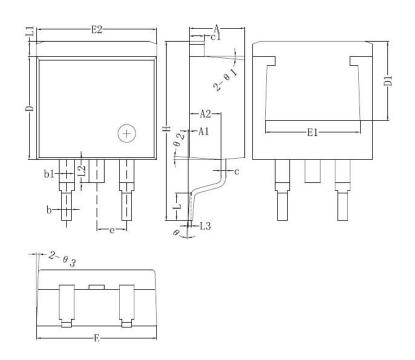






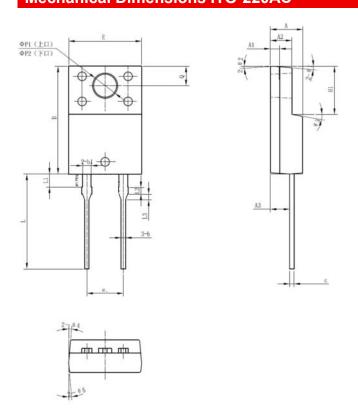


Mechanical Dimensions D²PAK



0	Dimensions in millimeters			
Symbol	Min.	Typical	Max.	
Α	4.55	4.70	4.85	
A1	0	0.10	0.25	
A2	2.59	2.69	2.89	
b	0.71	0.81	0.96	
b1		1.27		
С	0.36	0.38	0.61	
c1	1.17	1.27	1.37	
D	8.55	8.70	8.85	
D1	6.40			
E	10.01	10.16	10.31	
E1	7.6			
E2	9.98	10.08	10.18	
е		2.54		
Н	14.6	15.1	15.6	
L	2.00	2.30	2.70	
L1	1.17	1.27	1.40	
L2			2.20	
L3		0.25BSC		
е	0	-	8°	
e1		5°		
e2		4°		
e3		4°		

Mechanical Dimensions ITO-220AC



CVMDOL		Millimeters	
SYMBOL	MIN.	TYP.	MAX.
Α	4.30	4.50	4.70
A1	1.10	1.30	1.50
A2	2.50	3.00	3.20
A3	2.50	2.70	2.90
b	0.50	0.60	0.85
b1	1.10	1.20	1.35
С	0.50	0.60	0.85
D	14.80	15.00	15.20
E	9.96	10.16	10.36
е	-	5.10	-
H1	6.50	6.70	6.90
L	12.70	13.20	13.70
L1	1.60	1.80	2.00
L2	0.80	1.00	1.20
L3	0.60	0.80	1.00
ΦP1(上口)	3.30	3.50	3.70
ΦP2(下口)	2.99	3.19	3.39
Q	2.50	2.70	2.90
Θ1		5°	
Θ2		4°	
Θ3		10°	
Θ4		5°	
Θ5		5°	

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SICR5650 SICRB5650 SICRD5650 SICRF5650

Technical Data Data Sheet N1870, Draft 1





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